NSN 5962-00-166-6256

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 0.735 inches and 0.830 inches
Body Width:
Between 0.245 inches and 0.295 inches
Body Height:
Between 0.055 inches and 0.125 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+160.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and positive outputs and low power and 3-state output and wire-or outputs and expandable and
w/decoded output and w/buffered output and w/storage
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
11 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-20.0 volts power source and 5.0 volts power source
Time Rating Per Chacteristic:
10.00 nanoseconds propagation delay time, low to high level output and 10.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Fiig:

A458a0

Demilitarization: Yes - demil/mli